

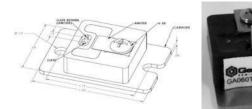
Silicon Carbide Thyristor

GA060TH65

| Carbiac | |
|---------|--|
| | |
| | |
| | |

| V _{FBM} | = | 6500 V |
|------------------------|---|---------|
| I _{T(AVM)} | = | 60 A |
| Q _{rr} | = | 2.95 µC |

Package





Features

- 6500 V Asymmetric SiC NPNP Thyristor
- 150 °C operating temperature
- Robust compact fully soldered package
- SOT-227 (ISOTOP) base plate form factor
- Fast turn on characteristics
- Lowest in class $Q_{rr}/I_{T(AVM)}$

Applications

- Grid Tied Solar Inverters
- Wind Power Inverters
- HVDC Power Conversion
- Utility Scale Power Conversion
- Trigger Circuits/Ignition Circuits

Maximum Ratings

| Parameter | Symbol | Conditions | Values | Unit |
|--------------------------------------|-----------------------------------|--------------------------------------|------------|------|
| Repetitive peak forward voltage | V _{FBM} | T _j = 25 °C | 6500 | V |
| Repetitive peak reverse voltage | V _{RBM} | T _j = 25 °C | 50 | V |
| Maximum average on-state current | I _{T(AVM)} | T _c ≤ 120 °C | 60 | А |
| RMS on-state current | I _{T(RMS)} | T _c ≤ 120 °C | 104 | А |
| Non-repetitive peak on-state current | I _{T,max} | T_c = 25 °C, t_p = 2 us, D = 0.1 | tbd | А |
| Power dissipation | P _{tot} | T _c = 25 °C | 919 | W |
| Operating and storage temperature | T _j , T _{stg} | | -55 to 150 | °C |

Electrical Characteristics

| Parameter | Symbol | Conditions | Values | | 11 | |
|-------------------------------------|---------------------|---|--------|------------|------|------|
| | | | min. | typ. | max. | Unit |
| Maximum peak on state voltage | V | I _κ = -60 A, T _j = 25 °C | | -3.90 | | V |
| | V _{KA(ON)} | I _κ = -60 A, Τ _j = 150 °C | | -3.70 | | |
| Anode-cathode threshold voltage | V _{KA(TO)} | T _j = 25 °C (150 °C) | | -3.1(-2.8) | | V |
| Anode-cathode slope resistance | R _{AK} | T _j = 25 °C (150 °C), I _κ = -60 A | | 9.4(9.5) | | mΩ |
| | I | V _{KA} = -6500 V, V _{GA} = 0 V, T _i = 25 °C | | 20 | | |
| Leakage current | L | V _{KA} = -6500 V, V _{GA} = 0 V, T _j = 150 °C | | 50 | | μA |
| Gate trigger current | Ι _{στ} | $T_{j} = 25 \text{ °C}, t_{p} = 10 \mu\text{s}$ | | -100 | | mA |
| Holding current | I _H | T _i = 25 °C | | tbd | | mA |
| Rise time | t _R | I _G = -3 A, V _{KA} = -2200 V | | 170 | | ns |
| Delay time | t _D | I _κ = -60 A, T _i = 25 °C | | 45 | | ns |
| Reverse recovery charge | Q _{rr} | · | | 2.95 | | μC |
| Recovered charge, 50% chord | Q _{ra} | dI/dt = 360 A/us, I_{κ} = -60 A, $V_{\kappa A}$ = 20 V | | 1.6 | | μC |
| Reverse recovery current | I _{rm} | dV/dt(re-app) = -362 V/us, T _i = 25 °C | | 15 | | А |
| Circuit commutated turn-off time | t _q | - | | 6.7 | | μs |
| Thermal Characteristics | | | | | | |
| Thermal resistance, junction - case | R _{thJC} | | | 0.136 | | °C/W |

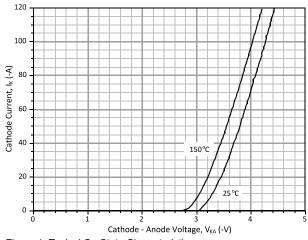
| Mechanical Properties | | | | |
|--------------------------|----------------|--|-----|----|
| Mounting torque for base | M _b | Heat sink surface must be optically flat | 1.5 | Nm |
| Mounting torque for top | M _t | | 1.3 | Nm |
| Weight | W. | | 30 | a |

1. Considering worst case Z_{th} conditions

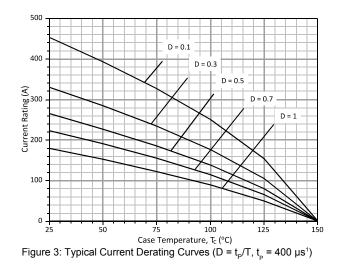
http://www.genesicsemi.com/index.php/sic-products/thyristors



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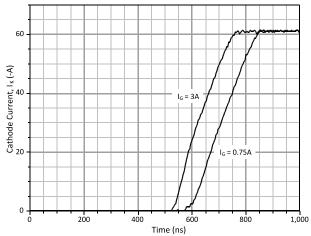


Figure 5: Typical Turn On Characteristics at 25 °C

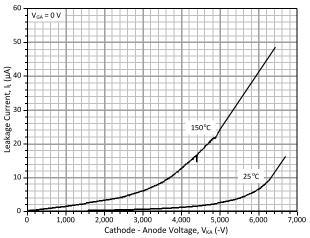
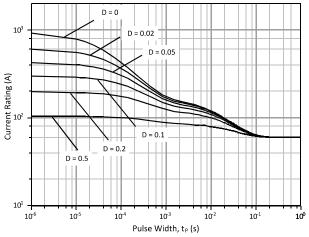
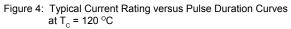


Figure 2: Typical Forward Blocking Characteristics





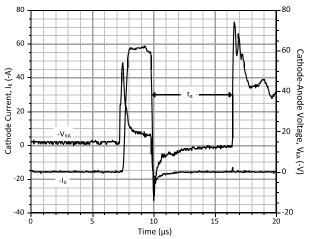


Figure 6: Typical Turn Off Characteristics at 25 °C

Preliminary Datasheet http://www.genesicsemi.com

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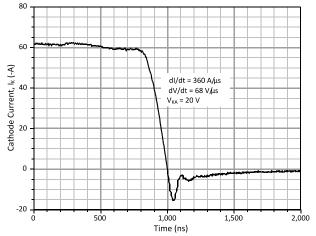


Figure 7: Typical Reverse Recovery Characteristics at 25 °C

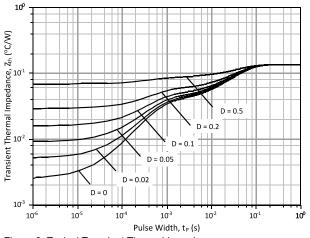


Figure 8: Typical Transient Thermal Impedance

| Revision History | | | | |
|------------------|----------|--------------------------|------------|--|
| Date | Revision | Comments | Supersedes | |
| 2010/11/10 | 1 | First generation release | | |
| | | | | |

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